

isc N-Channel MOSFET Transistor

AOT264L

• FEATURES

- Drain Current –I_D= 140A@ T_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)}$ = 3.2m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

• Be suitable for synchronous rectification for server and general purpose applications

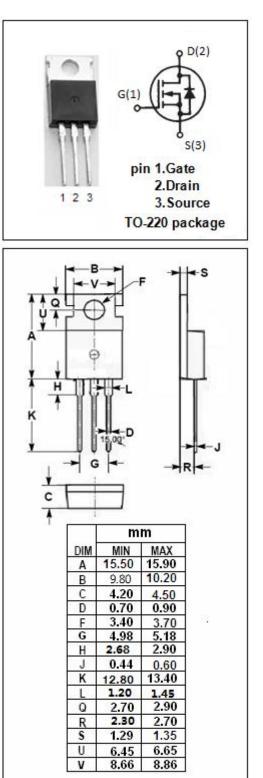
| SYMBOL | PARAMETER VALUE | | UNIT | | | |
|------------------|---|-----|------|--|--|--|
| V _{DSS} | Drain-Source Voltage 60 | | V | | | |
| V _{GS} | Gate-Source Voltage | ±20 | V | | | |
| ID | Drain Current-Continuous | 140 | A | | | |
| I _{DM} | Drain Current-Single Pulsed | 480 | A | | | |
| Po | Total Dissipation @Tc=25°C 333 | | W | | | |
| Tj | Max. Operating Junction Temperature -55~175 | | °C | | | |
| T _{stg} | Storage Temperature -55~175 | | °C | | | |

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 0.45 | °C/W |

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|----------------------|--------------------------------|--|-----|------------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; ID = 250 μ A | 60 | | V |
| V _{GS} (th) | Gate Threshold Voltage | V _{DS} = V _{GS} ; ID = 250 μ A | 2.2 | 3.2 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 20A V _{GS} = 10V; I _D = 20A;T _J = 125℃ | | 3.2 4.8 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V_{GS} = ±20V; V_{DS} = 0V | | ±100 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = 60V; V _{GS} = 0V V _{DS} = 60V; V _{GS} = 0V; T _J = 55℃ | | 1 5 | μA |
| V _{SD} | Diode forward voltage | Is= 1A; V _{GS} = 0V | | 1 | V |

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